onsemi

Low Voltage Comparator FAN156

Description

The FAN156 is a low–power single comparator that typically consumes less than 10 μ A of supply current. It is guaranteed to operate at a low voltage of 1.6 V and is fully operational up to 5.5 V, making it convenient for use in 1.8, 3.0 V, and 5.0 V systems.

The FAN156 has a complementary push–pull P– and N–channel output stage capable of driving a rail–to–rail output swing with a load ranging up to 5.0 mA.

Features

- Low Supply Current: I_{DD} 6 µA (Typical)
- Single Power Supply Operation
- Wide Common–Mode Input Voltage Range
- Push–Pull Output Circuit
- Low Input Bias Current
- Internal Hysteresis
- Packaged in MicroPak[™] 6
- This is a Pb–Free Device

Applications

- Mobile Phones
- Alarm and Security Systems
- Personal Digital Assistants

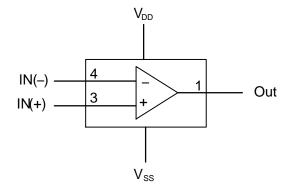


Figure 1. Functional Diagram



SIP6 1.45x1.0 CASE 127EB

MARKING DIAGRAM

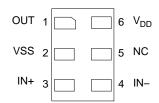


- CN = Specific Device Code
- &K = 2-Digits Lot Run Traceability Code
- &2 = 2–Digit Date Code
- &Z = Assembly Plant Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.

PIN CONFIGURATION





PIN DEFINITIONS

Pin #	Name	Description
1	OUT	Comparator Output
2	V _{SS}	Negative Supply Voltage
3	IN+	Non–Inverting Input
4	IN–	Inverting Input
5	NC	No Connect
6	V _{DD}	Positive Supply Voltage

FUNCTION TABLE

Inputs	Outputs
IN(-) > IN(+)	Output LOW
IN(+) > IN(-)	Output HIGH

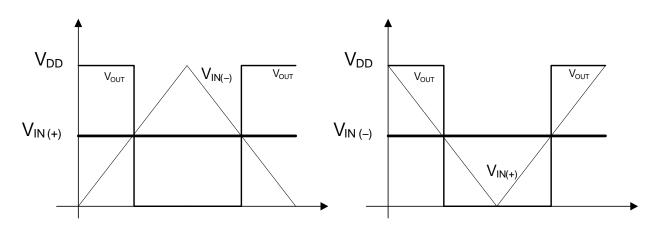


Figure 3. V_{IN} vs. V_{OUT}

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Condition	Min.	Max.	Unit
V_{DD} to V_{SS}	Supply Voltage		-3.0	+3.0	V
			0	6.0	
DVIN	Differential Input Voltage			±6	
V _{IN}	Input Voltage			V_{SS} to V_{DD}	V
ts	Output Short Circuit Duration (Note 1)			Indefinite	S
ТJ	Junction Temperature			+150	°C
T _{STG}	Storage Temperature Range		-65	+150	°C
PD	Power Dissipation			194	mW
Θ_{JA}	Thermal Resistance			335	°C/W
ESD	IEC 61000-4-2 System ESD	Air Gap		15	kV
		Contact		8	
	JEDEC JESD22-A114, Human Body	All Pins		8	
	Model	Pin to Pin: IN(–), IN(+) to V _{DD} or VSS		12	1
	JEDEC JESD22–C101, Charged Device Model	All Pins		2	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. The maximum total power dissipation must not be exceeded.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Condition	Min.	Max.	Unit
V_{DD} to V_{SS}	Power Supply		-2.75	+2.75	V
			0	5.50	
V _{DD}	Power Supply	V _{SS} 0 V	1.6	5.5	V
V _{IN}	Input Voltage			$\rm V_{SS}$ to $\rm V_{DD}$	V
I _{OH} /I _{OL}	Output Sink/Source Current	V _{DD} 5.0 V		5	mA
		V _{DD} 3.0 V		3	
		V _{DD} 1.6 V		1	
T _A	Operating Temperature, Free Air		-40	+85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
V _{DD} = 5.5 V, V	$T_{SS} = GND$, and $T_A = +25^{\circ}C$					
V _{HYS}	Input Hysteresis	$V_{CM} = 0.5 V_{DD}$		4		mV
V _{IO}	Input Offset Voltage (Note 2)	$V_{CM} = 0.5 V_{DD}$	–15	±1	+15	mV
I _{IO}	Input Offset Current			10		pА
lı	Input Bias Current			10		pА
V _{CM}	Common Mode Input Voltage		V _{SS}		V _{DD}	V
CMRR	Common Mode Rejection Ratio (Note 3)	$V_{CM} = V_{DD}$		68		dB
I _{DD}	Supply Current			6	17	μΑ
PSRR	Power Supply Rejection Ratio (Note 3)	$\Delta V_{DD} = 0.5 V$	45	80		dB
I _{OS}	Output Short Circuit Current	$V_{O} = V_{DD}$		60		mA
		$V_{O} = V_{SS}$		90		
V _{OL}	Low-Level Output Voltage	I _{SINK} = 5.0 mA		0.1	0.3	V
V _{OH}	High-Level Output Voltage	I _{SOURCE} = 5.0 mA	5.2	5.4		V
t _{PLH}	Propagation Delay (Turn–On)	Overdrive 20 mV, $C_L = 15 \text{ pF}$		0.40		μS
t _{PHL}	Propagation Delay (Turn–Off)	Overdrive = 20 mV, $C_L = 15 \text{ pF}$		0.42		μs
t _{TLH}	Response Time, Output Rise/Fall	C _L = 50 pF		4.0		ns
t _{THL}	(Note 4)			5.4		
/ _{DD} = 3 V, V _S	_S = GND, and T _A = +25°C	•	•			
V _{HYS}	Input Hysteresis	$V_{CM} = 0.5 V_{DD}$		4		mV
V _{IO}	Input Offset Voltage (Note 2)	$V_{CM} = 0.5 V_{DD}$	-15	±1	+15	mV
I _{IO}	Input Offset Current			10		pА
l	Input Bias Current			10		pА
V _{CM}	Common Mode Input Voltage		V _{SS}		V _{DD}	V
CMRR	Common Mode Rejection Ratio (Note 3)	$V_{CM} = V_{DD}$		60		dB
I _{DD}	Supply Current			5.5	15.0	μΑ
PSRR	Power Supply Rejection Ratio (Note 3)	$\Delta V_{DD} = 0.5 V$	45	80		dB
I _{OS}	Output Short Circuit Current	$V_{O} = V_{DD}$		27		mA
		$V_{O} = V_{SS}$		35		
V _{OL}	Low-Level Output Voltage	I _{SINK} = 3.0 mA		0.15	0.35	V
V _{OH}	High-Level Output Voltage	I _{SOURCE} = 3.0 mA	2.65	2.85		V
t _{PLH}	Propagation Delay (Turn-On)	Overdrive = 20 mV, $C_L = 15 \text{ pF}$		0.45		μs
t _{PHL}	Propagation Delay (Turn–Off)	Overdrive = 20 mV, $C_L = 15 \text{ pF}$		0.47		μs
t _{TLH}	Response Time, Output Rise/Fall (Note 4)			6.1	1	ns
t _{THL}	1			6.2		
	$I_{SS} = GND$, and $T_A = +25^{\circ}C$	•	-			-
V _{HYS}	Input Hysteresis	$V_{CM} = 0.5 V_{DD}$		3.5		mV
V _{IO}	Input Offset Voltage (Note 2)	$V_{CM} = 0.5 V_{DD}$	-15	±1	+15	mV
l _{IO}	Input Offset Current			10		pА
I	Input Bias Current			10		рА
V _{CM}	Common Mode Input Voltage		V _{SS}		V _{DD}	V
CMRR	Common Mode Rejection Ratio (Note 3)	V _{CM} = V _{DD}		56		dB

ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
V _{DD} = 1.6 V, V	_{SS} = GND, and T _A = +25°C					
I _{DD}	Supply Current			5	15	μΑ
PSRR	Power Supply Rejection Ratio (Note 3)	$\Delta V_{DD} = 0.5 V$	45	80		dB
I _{OS}	Output Short Circuit Current	$V_{O} = V_{DD}$		5.5		mA
		$V_{O} = V_{SS}$		7.5		
V _{OL}	Low-Level Output Voltage	I _{SINK} = 5.0 mA		0.10	0.25	V
V _{OH}	High-Level Output Voltage	I _{SOURCE} = 5.0 mA	1.35	1.50		V
t _{PLH}	Propagation Delay (Turn–On)	Overdrive 20 mV, $C_L = 15 \text{ pF}$		0.52		μS
t _{PHL}	Propagation Delay (Turn–Off)	Overdrive = 20 mV, $C_L = 15 \text{ pF}$		0.54		μs
t _{TLH}	Response Time, Output Rise/Fall	C _L = 50 pF		16.5		ns
t _{THL}	(Note 4)			13.0]

Differential input switching level is guaranteed at the minimum or maximum offset voltage, minus or plus half the maximum hysteresis voltage.
Guaranteed by design and characterization data.
Input signal: 1 kHz, square-wave signal with 10 ns edge rate.

TYPICAL PERFORMANCE CHARACTERISTICS

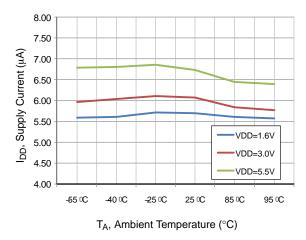


Figure 4. Supply Current vs. Temperature

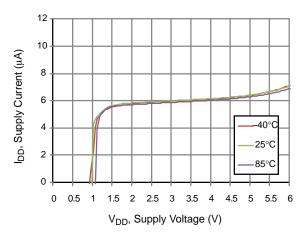


Figure 6. Supply Current vs. Supply Voltage

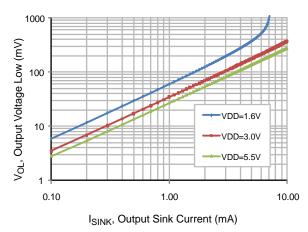


Figure 8. Output LOW vs. Output Drive Current

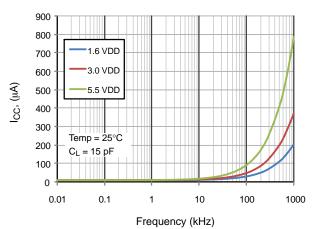


Figure 5. Supply Current vs. Output

Transition Frequency

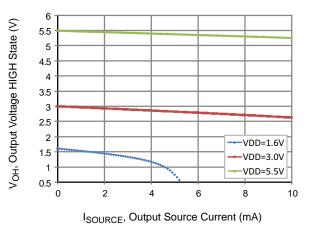
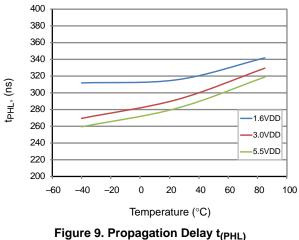
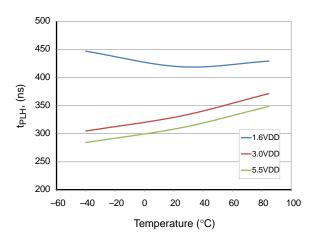


Figure 7. Output HIGH vs. Output Drive Current





TYPICAL PERFORMANCE CHARACTERISTICS (continued)





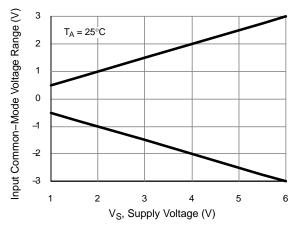


Figure 12. Input Common–Mode Voltage Range vs. Supply Voltage

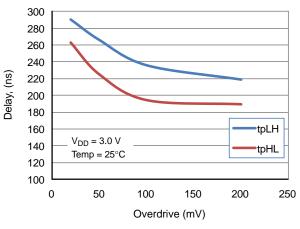


Figure 11. Propagation Delay vs. Input Overdrive

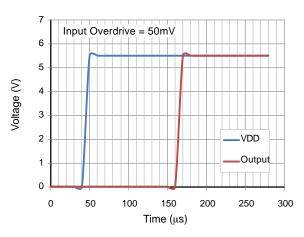


Figure 13. Power–Up Delay

ORDERING INFORMATION

Device	Operating Temperature Range	Top Mark	Package	Shipping [†]
FAN156L6X	–40°C to +85°C	CN	6–Lead, SIP6 1.45x1.0 (MicroPak [™]) (Pb–Free)	5000 / Tape & Reel

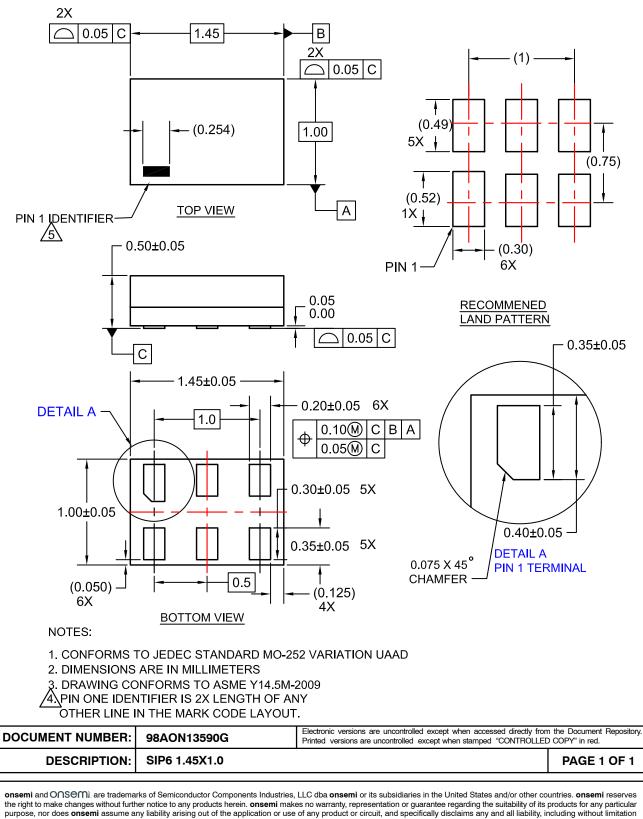
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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